Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-908-1997

	Inclosure Material:
(Glass and metal
(Overall Length:
(0.800 inches
•	Terminal Length:
	1.000 inches
(Overall Diameter:
(0.400 inches
ļ	Function For Which Designed:
1	Voltage variable capacitor
ļ	Mounting Method:
-	Terminal
	Features Provided:
	Hermetically sealed case
;	Semiconductor Material:
;	Silicon
1	Voltage Rating In Volts Per Characteristic:
;	30.0 reverse voltage, peak
	Power Rating Per Characteristic:
(0.5 watts small-signal input power, common-collector preset
(Capacitance Rating In Picofarads:
4	470.0
	Maximum Operating Tempurature Per Measurement Point:
	150.0 degrees celsius ambient air
•	Terminal Type And Quantity:
	2 uninsulated wire lead
;	Shelf Life:
	N/a
l	Unit Of Measure:
•	-
	Demilitarization:
	No
	Fiig:
	A110a0